

Technical Data

DIODE



maximum ratings

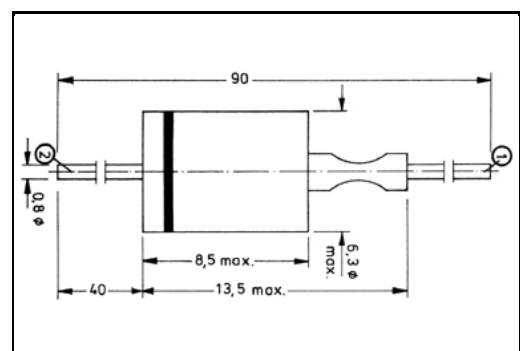
Voltage, Reverse (VZ)	6.8	V	NO.	1N3016B
Voltage, Reverse Peak (VRM)		V	TYPE	1W-ZENER
Current at VR = 0V (IO)		A		
Current Average Rectified (IF)		A		
Current Surge Peak (IZM)	0.14	A	CASE	DO-13
Current, Surge (IFM) at tp =		A		
Max. Power Dissipation (PT) at TC = 25 °C	1.0	W		
Max. Thermal Resistance (Rth J-A)	150.0	°C/W		
Max. Junction Temperature (TJ)	175.0	°C		

PERFORMANCE CHARACTERISTICS at $T_c = 25^\circ\text{C}$, unless otherwise noted

NO.	SYMBOL	CONDITIONS	MIN.	MAX.	UNITS
1.	VZ	$I_Z = 37.0 \text{ mA}$, $t_p = 100.0 \mu\text{s}$, $\text{dc} = 0.1 \%$	6.64	7.14	V
2.	RZ	$I_Z = 37.0 \text{ mA}$, $\Delta I_Z = 10.0\% I_Z$, $f = 1.0 \text{ kHz}$	-	3.5	Ω
3.	RZ	$I_Z = 1.0 \text{ mA}$	-	700.0	Ω
4.	IR	$V_R = 5.2 \text{ V}$	-	10.0	μA
5.	VF	$I_F = 200.0 \text{ mA}$ (1)	-	1.5	V
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17.					
18.					
19.					
20.					

Notes (1) pulse-tested $t_p \leq 300 \mu\text{s}$, duty cycle $\leq 2 \%$

DIMENSIONS
in mm



Marking 1N3016B
Customer GENERAL PURPOSE